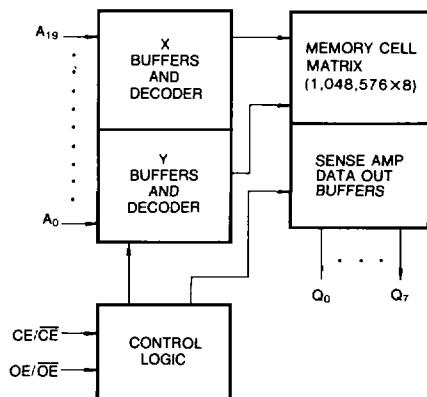


8M-Bit (1M × 8) CMOS MASK ROM**FEATURES**

- 1,048,576 × 8 bit organization
- Fast access time: 150ns (max.)
- Supply voltage: single +5V
- Current consumption
 - Operating: 50mA (max.)
 - Standby : 50μA (max.)
- Fully static operation
- All inputs and outputs TTL compatible
- Three state outputs
- Polarity programmable chip enable and output enable pin
- Package: 32-pin, 600 mil, plastic DIP (JEDEC standard)
32-pin, 525 mil, plastic SOP

FUNCTIONAL BLOCK DIAGRAM**GENERAL DESCRIPTION**

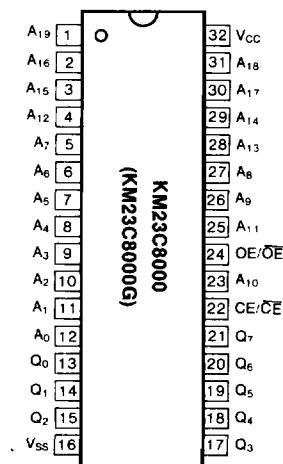
The KM23C8000 is a fully static mask programmable ROM organized 1,048,576×8 bit. It is fabricated using silicon-gate CMOS process technology.

This device operates with a 5V single power supply, and all inputs and outputs are TTL compatible. Because of its asynchronous operation, it requires no external clock assuring extremely easy operation.

It is suitable for use in program memory of microprocessor, and data memory, character generator.

The KM23C8000 is packaged in a 32-DIP, and the KM23C8000G in a 32-SOP, provides polarity programmable CE and OE buffer as user option mode.

4

PIN CONFIGURATION

| Pin Name | Pin Function |
|---------------------------------|----------------|
| A ₀ -A ₁₉ | Address Inputs |
| Q ₀ -Q ₇ | Data Outputs |
| CE/CĒ* | Chip Enable |
| OE/OĒ* | Output Enable |
| Vcc | Power (+5V) |
| Vss | Ground |

* User Selectable Polarity

ABSOLUTE MAXIMUM RATINGS

| Item | Symbol | Rating | Unit |
|--|-------------------|--------------|------|
| Voltage on Any Pin Relative to V _{SS} | V _{IN} | -0.3 to +7.0 | V |
| Temperature Under Bias | T _{bias} | -10 to +85 | °C |
| Storage Temperature | T _{stg} | -55 to +150 | °C |

* Permanent device damage may occur if "ABSOLUTE MAXIMUM RATINGS" are exceeded. Functional Operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS (Voltage reference to V_{SS}, T_A=0 to 70°C)

| Item | Symbol | Min | Typ | Max | Unit |
|--------------------------------|-----------------|------|-----|----------------------|------|
| Supply Voltage | V _{CC} | 4.5 | 5.0 | 5.5 | V |
| Supply Voltage | V _{SS} | 0 | 0 | 0 | V |
| Input High Voltage, All Inputs | V _{IH} | 2.2 | — | V _{CC} +0.3 | V |
| Input Low Voltage, All Inputs | V _{IL} | -0.3 | — | 0.8 | V |

DC AND OPERATING CHARACTERISTICS

(Recommended operating conditions unless otherwise noted)

| Parameter | Symbol | Test Conditions | | Min | Max | Unit |
|---------------------------|------------------|--|----------|-----|-----|------|
| Operating Current | I _{CC1} | $\overline{CE}=\overline{OE}=V_{IL}$ | f=6.7MHz | — | 50 | mA |
| | I _{CC2} | all output open | | — | 25 | mA |
| Standby Current (TTL) | I _{SB1} | $\overline{CE}=V_{IH}$, all output open | | — | 1 | mA |
| Standby Current (CMOS) | I _{SB2} | $\overline{CE}=V_{CC}$, all output open | | — | 50 | μA |
| Input Leakage Current | I _{LI} | $V_{IN}=0$ to V_{CC} | | — | 10 | μA |
| Output Leakage Current | I _{LO} | $V_{OUT}=0$ to V_{CC} | | — | 10 | μA |
| Output High Voltage Level | V _{OH} | I _{OH} =-400μA | | 2.4 | — | V |
| Output Low Voltage Level | V _{OL} | I _{OL} =2.1 mA | | — | 0.4 | V |

CAPACITANCE (T_A=25°C, f=1.0MHz)

| Item | Symbol | Test Conditions | Min | Max | Unit |
|--------------------|------------------|----------------------|-----|------|------|
| Output Capacitance | C _{OUT} | V _{OUT} =0V | — | 10.0 | pF |
| Input Capacitance | C _{IN} | V _{IN} =0V | — | 10.0 | pF |

Note: Capacitance is periodically sampled and not 100% tested.

MODE SELECTION

| CE/ \overline{CE} | OE/ \overline{OE} | Mode | Data | Power |
|---------------------|---------------------|-----------|--------|---------|
| L/H | X | Standby | High-Z | Standby |
| | L/H | Operating | High-Z | Active |
| | H/L | Operating | Dout | Active |

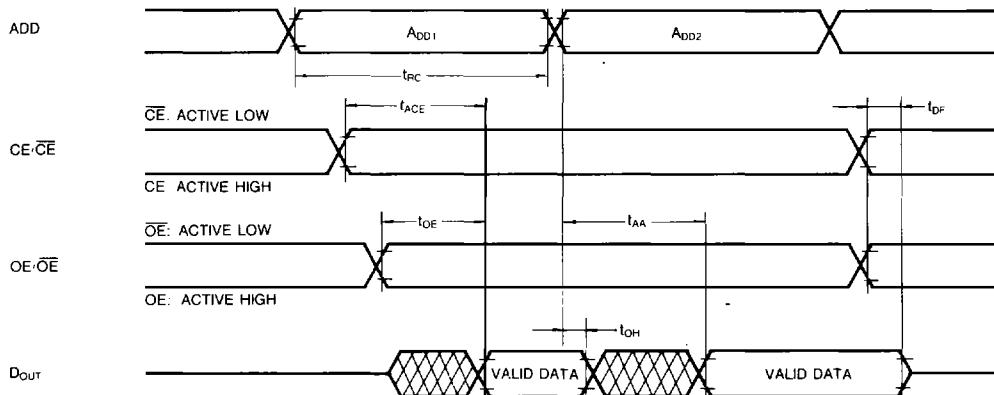
AC CHARACTERISTICS ($T_a=0^\circ$ to $+70^\circ\text{C}$, $V_{CC}=5\text{V}\pm 10\%$, unless otherwise noted.)**TEST CONDITIONS**

| Item | Value |
|--------------------------------|----------------------------------|
| Input Pulse Levels | 0.6V to 2.4V |
| Input Rise and Fall Times | 10ns |
| Input and Output timing Levels | 0.8V and 2.0V |
| Output Loads | 1 TTL Gate and $CL=100\text{pF}$ |

READ CYCLE

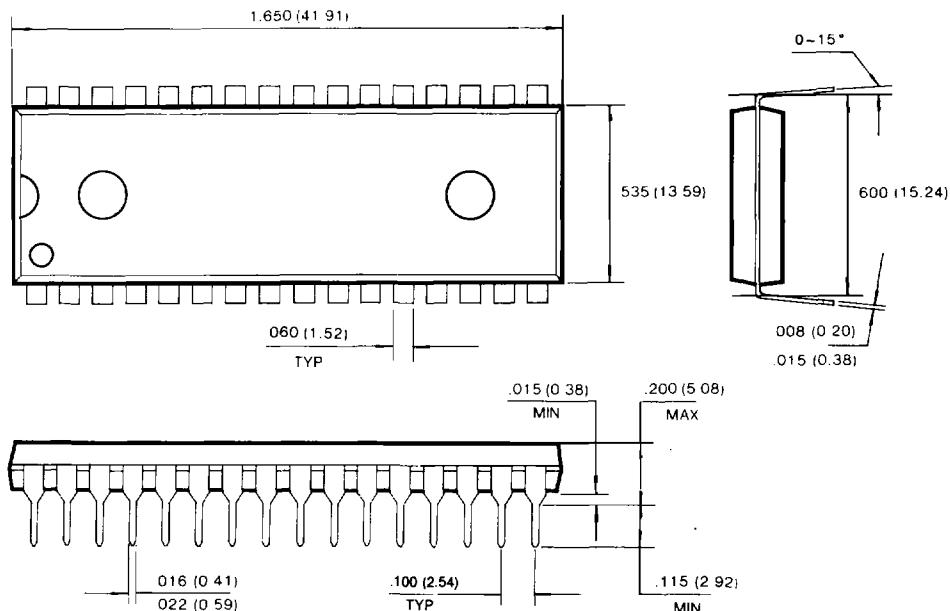
| Parameter | Symbol | KM23C8000(G)-15 | | KM23C8000(G)-20 | | KM23C8000(G)-25 | | Unit |
|---|-----------|-----------------|-----|-----------------|-----|-----------------|-----|------|
| | | Min | Max | Min | Max | Min | Max | |
| Read Cycle Time | t_{RC} | 150 | | 200 | | 250 | | ns |
| Chip Enable Access Time | t_{ACE} | | 150 | | 200 | | 250 | ns |
| Address Access Time | t_{AA} | | 150 | | 200 | | 250 | ns |
| Output Enable Access Time | t_{OE} | | 70 | | 90 | | 110 | ns |
| Output or Chip Disable to Output High-Z | t_{DF} | | 60 | | 70 | | 80 | ns |
| Output Hold from Address Change | t_{OH} | 10 | | 10 | | 10 | | ns |

4

TIMING DIAGRAM**READ**

PACKAGE DIMENSIONS**32 LEAD PLASTIC DUAL IN LINE PACKAGE (KM23C8000)**

Units: Inches (millimeters)

**32 LEAD SMALL OUTLINE PACKAGE (KM23C8000G)**